

SN65MLVD048 クワッド チャネル M-LVDS レシーバ

1 特長

- 250Mbps までの信号速度、125MHz までのクロック周波数に対する低電圧差動 30Ω~55Ω ラインレシーバ¹
- Type-1 レシーバは、25mV の入力スレッショルドヒステリシス付き
- Type-2 レシーバは、断線およびアイドルバス条件を検出するための 100mV のオフセットスレッショルドを提供
- レシーバ入力同相電圧範囲が -1V~3.4V と広いいため、2V のグラウンドノイズを許容
- マルチポイントトポロジで M-LVDS 規格 TIA/EIA-899 に適合またはそれを上回る性能
- $V_{CC} \leq 1.5V$ のとき高入力インピーダンス
- 強化 ESD 保護機能:すべてのピンで 7kV HBM
- 48ピン 7 X 7 QFN (RGZ)

2 アプリケーション

- バックプレーンとケーブルを介した並列マルチポイントデータおよびクロック伝送
- 携帯基地局
- 中央局向けスイッチ
- ネットワークスイッチおよびルータ

3 概要

SN65MLVD048 は、クワッド チャネル M-LVDS レシーバです。このデバイスは、最高 250Mbps の信号速度で動作するよう最適化された TIA/EIA-899 (M-LVDS) 規格に完全準拠して設計されています。各レシーバチャンネルは、受信イネーブル (\overline{RE}) によって制御されます。 $\overline{RE} = \text{LOW}$ のとき、対応するチャンネルがイネーブルになり、 $\overline{RE} = \text{HIGH}$ のとき、対応するチャンネルがディセーブルになります。

M-LVDS 規格では、Type-1 および Type-2 という 2 種類のレシーバが定義されています。Type-1 レシーバは、ゼロを中心とするスレッショルドで、25mV のヒステリシスを設けて、入力が失われた場合の出力発振を防止します。Type-2 レシーバは、オフセットスレッショルドを使用してフェイルセーフを実装しています。レシーバ出力はスルーレート制御されているため、大きな電流サージに伴う EMI およびクロストークの影響を低減できます。

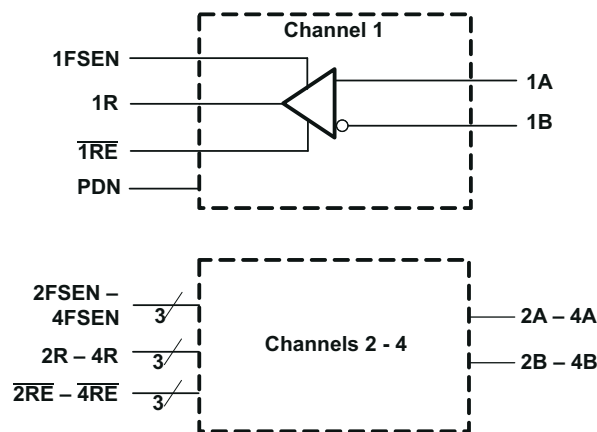
これらのデバイスは、-40°C~85°Cでの動作が規定されています。

パッケージ情報

部品番号	パッケージ ⁽¹⁾	パッケージサイズ ⁽²⁾
SN65MLVD048	VQFN (RGZ, 48)	7mm × 7mm

(1) 詳細については、[セクション 10](#) を参照してください。

(2) パッケージサイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



論理図 (正論理)

¹ ラインの信号速度とは、1秒あたりの電圧遷移回数。単位は bps (ビット毎秒)



Table of Contents

1 特長	1	5.9 Typical Characteristics.....	7
2 アプリケーション	1	6 Parameter Measurement Information	11
3 概要	1	7 Device Functional Modes	15
4 Pin Configuration and Functions	3	8 Device and Documentation Support	16
5 Specifications	4	8.1 ドキュメントの更新通知を受け取る方法.....	16
5.1 Absolute Maximum Ratings.....	4	8.2 サポート・リソース.....	16
5.2 ESD Ratings.....	4	8.3 Trademarks.....	16
5.3 Recommended Operating Conditions.....	4	8.4 静電気放電に関する注意事項.....	16
5.4 Package Dissipation Ratings.....	4	8.5 用語集.....	16
5.5 Thermal Information.....	5	9 Revision History	16
5.6 Device Electrical Characteristics.....	5	10 Mechanical, Packaging, and Orderable Information	16
5.7 Receiver Electrical Characteristics.....	5		
5.8 Receiver Switching Characteristics.....	6		

4 Pin Configuration and Functions

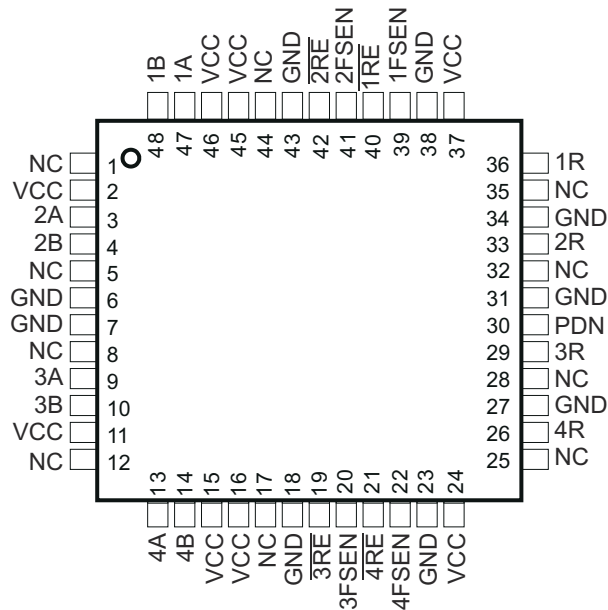


図 4-1. RGZ Package (Top View)

PIN		I/ O ⁽¹⁾	DESCRIPTION
NAME	NO.		
1R—4R	36, 33, 29, 26	O	Data output from receivers
1A—4A	47, 3, 9, 13	I/O	M-LVDS bus non-inverting input/output
1B—4B	48, 4, 10, 14	I/O	M-LVDS bus inverting input/output
GND	6, 7, 18, 23, 27, 31, 34, 38, 43	I	Circuit ground. ALL GND pins must be connected to ground.
V _{CC}	2, 11, 15, 16, 24, 37, 45, 46	I	Supply voltage. ALL VCC pins must be connected to supply.
$\overline{1RE}$ – $\overline{4RE}$	40, 42, 19, 21	I	Receiver enable, active low, enables individual receivers. When this pin is left floating, internally this pin will be pulled to logic HIGH.
1FSEN–4FSEN	39, 41, 20, 22	I	Failsafe enable pin. When this pin is left floating, internally this pin will be pulled to logic HIGH. This pin enables the Type 2 receiver for the respective channel. xFSEN = L → Type 1 receiver inputs xFSEN = H → Type 2 receiver inputs
PDN	30		Power Down pin. When this pin is left floating, internally this pin will be pulled to logic LOW. When PDN is HIGH, the device is powered up. When PDN is LOW, the device overrides all other control and powers down. All outputs are Hi-Z
NC	1, 5, 8, 12, 17, 25, 28, 32, 35		Not Connected
NC	44		Not Connected. Internal TI Test pin. This pin must be left unconnected.
PowerPAD™	–		Connected to GND

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾	-0.5		4	V
	Input voltage range	RE, FSEN		4	V
		A or B		4	V
	Output voltage range	R		4	V
P _D	RE at 0V, C _L = 15pF, V _{ID} = 400mV, 125MHz			339	mW
T _{stg}	Storage Temperature	-65		150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±7000
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1500

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	3	3.3	3.6	V
V _{IH}	High-level input voltage	2		V _{CC}	V
V _{IL}	Low-level input voltage	GND		0.8	V
V _A or V _B	Voltage at any bus terminal	-1.4		3.8	V
V _{ID}	Magnitude of differential input voltage	0.05		V _{CC}	V
V _{IC}	Differential common-mode input voltage	-1		3.4	V
R _L	Differential load resistance	30	50		Ω
1/t _{UI}	Signaling rate			250	Mbps
T _A	Operating free-air temperature	-40		85	°C

5.4 Package Dissipation Ratings

PACKAGE ⁽¹⁾	PCB TYPE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽²⁾ ABOVE T _A = 25°C	T _A = 85°C POWER RATING
48-Pin QFN (RGZ)	Low-K	1298 mW	12.98 mW/°C	519 mW
	High-K	3448 mW	34.48 mW/°C	1379 mW

- (1) The thermal dissipations are in the consideration of soldering down the powerPAD without via on each type of boards.
- (2) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

5.5 Thermal Information

THERMAL METRIC ⁽¹⁾		RGZ	UNIT
		48-Pins	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	25.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	15.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	8.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	0.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	8.7	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	1.4	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.6 Device Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
I_{CC}	Supply current	\overline{RE} at 0V for all channels $C_L = 15\text{pF}$, $V_{ID} = 400\text{mV}$, 125MHz		86	94	mA
	Power down	PDN = L		0.75	1.5	mA

(1) All typical values are at 25°C and with a 3.3V supply voltage.

5.7 Receiver Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IT+}	Positive-going differential input voltage threshold	Type 1			35	mV
		Type 2			135	
V_{IT-}	Negative-going differential input voltage threshold	Type 1	See 表 6-1 and 表 6-2		-35	mV
		Type 2			65	
V_{HYS}	Differential input voltage hysteresis ($V_{IT+} - V_{IT-}$)	Type 1			25	mV
		Type 2			0	
V_{OH}	High-level output voltage	$I_{OH} = -8\text{mA}$	2.4			V
V_{OL}	Low-level output voltage	$I_{OL} = 8\text{mA}$			0.4	V
I_{IH}	High-level input current	$V_{IH} = 2\text{V}$ to V_{CC}	-10			μA
I_{IL}	Low-level input current	$V_{IL} = \text{GND}$ to 0.8V	-10			μA
I_{OZ}	High-impedance output current	$V_O = 0\text{V}$ or V_{CC}	-10		15	μA
I_A or I_B	Receiver input current	One input (V_A or V_B) = -1.4V or 3.8V, Other input = 1.2V	-20		20	μA
I_{AB}	Receiver differential input current ($I_A - I_B$)	$V_A = V_B = -1.4\text{V}$ or 3.8V	-4		4	μA
$I_{A(OFF)}$ or $I_{B(OFF)}$	Receiver input current	One input (V_A or V_B) = -1.4V or 3.8V, Other input = 1.2V, $V_{CC} = \text{GND}$ or 1.5V	-32		32	μA
$I_{AB(OFF)}$	Receiver power-off differential input current ($I_A - I_B$)	$V_A = V_B = -1.4\text{V}$ or 3.8V, $V_{CC} = \text{GND}$ or 1.5V	-4		4	μA
C_A or C_B	Input capacitance	$V_I = 0.4\sin(30E6\pi t) + 0.5\text{V}$, ⁽²⁾ Other input at 1.2V		5		pF
C_{AB}	Differential input capacitance	$V_{AB} = 0.4\sin(30E6\pi t) + 0.5\text{V}$ ⁽²⁾			3	pF
$C_{A/B}$	Input capacitance balance, (C_A/C_B)		0.99		1.01	

(1) All typical values are at 25°C and with a 3.3V supply voltage.

(2) HP4194A impedance analyzer (or equivalent)

5.8 Receiver Switching Characteristics

over recommended operating conditions (unless otherwise noted)

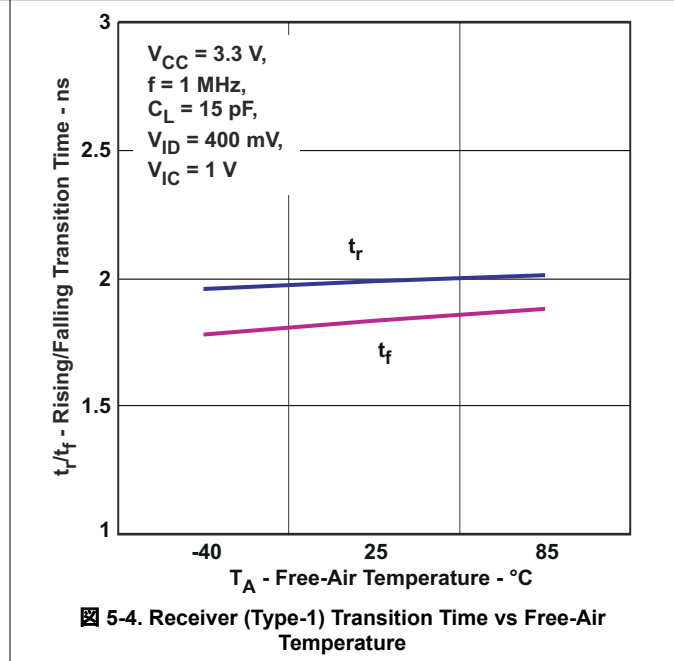
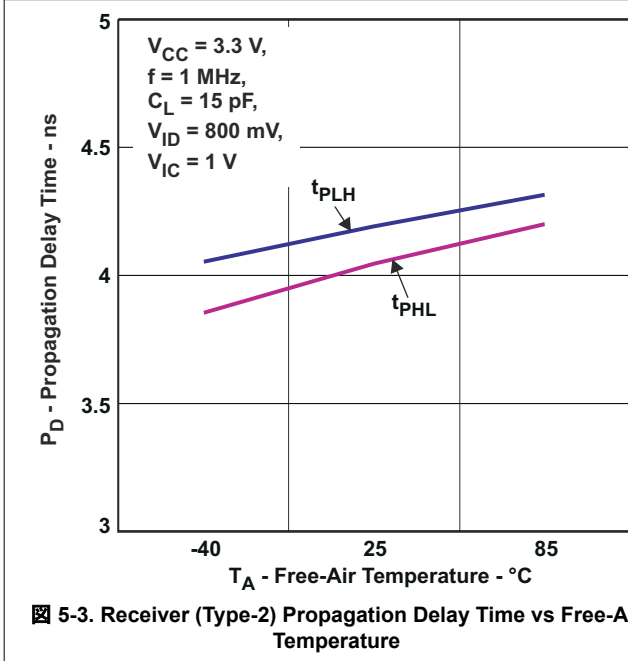
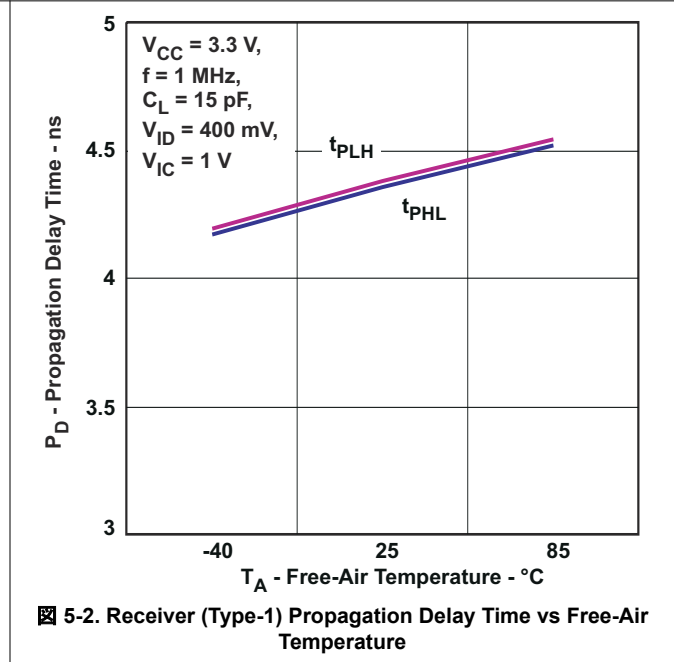
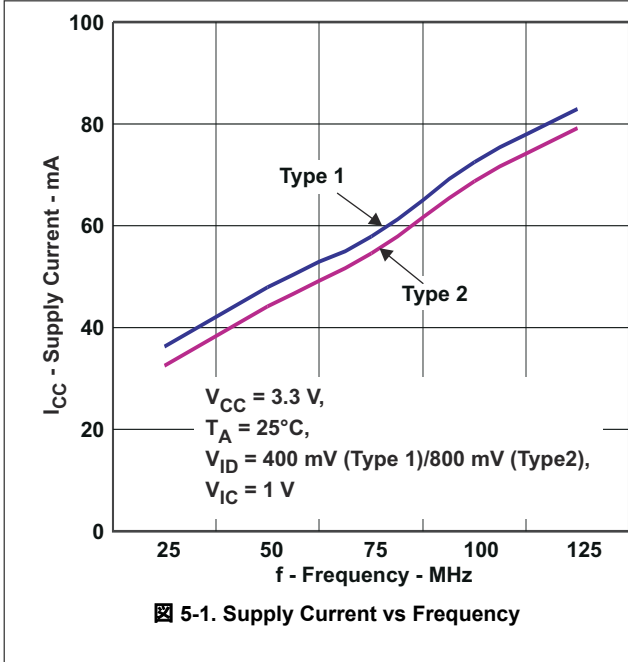
PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT	
t _{PLH}	Propagation delay time, low-to-high-level output	C _L = 15pF, See 6-2	2		6	ns	
t _{PHL}	Propagation delay time, high-to-low-level output		2		6	ns	
t _r	Output signal rise time		1		2.3		
t _f	Output signal fall time		1		2.3	ns	
t _{sk(p)}	Pulse skew (t _{PHL} – t _{PLH})		Type 1		35	270	ps
			Type 2		150	460	
t _{sk(pp)}	Part-to-part skew				800	ps	
t _{jit(per)}	Period jitter, rms (1 standard deviation) ⁽²⁾		All channels switching, 125MHz clock input ⁽³⁾ , See 6-4			6	ps
t _{jit(c-c)}	Cycle-to-cycle jitter, rms ⁽²⁾					13	ps
t _{jit(det)}	Deterministic jitter ⁽²⁾		Type 1			800	ps
		Type 2			945	ps	
t _{jit(ran)}	Random jitter ⁽²⁾	Type 1			9	ps	
		Type 2			8	ps	
t _{PZH}	Enable time, high-impedance-to-high-level output	C _L = 15pF, See 6-3			15	ns	
t _{PZL}	Enable time, high-impedance-to-low-level output	C _L = 15pF, See 6-3			15	ns	
t _{PHZ}	Disable time, high-level-to-high-impedance output	C _L = 15pF, See 6-3			10	ns	
t _{PLZ}	Disable time, low-level-to-high-impedance output	C _L = 15pF, See 6-3			10	ns	

(1) All typical values are at 25°C and with a 3.3V supply voltage.

(2) Jitter is ensured by design and characterization. Stimulus jitter has been subtracted from the numbers.

(3) t_r = t_f = 0.5ns (10% to 90%)

5.9 Typical Characteristics



5.9 Typical Characteristics (continued)

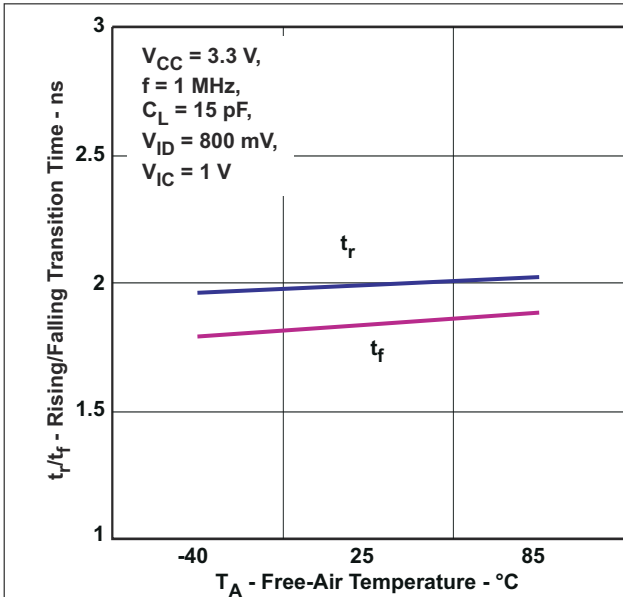


图 5-5. Receiver (Type-2) Transition Time vs Free-Air Temperature

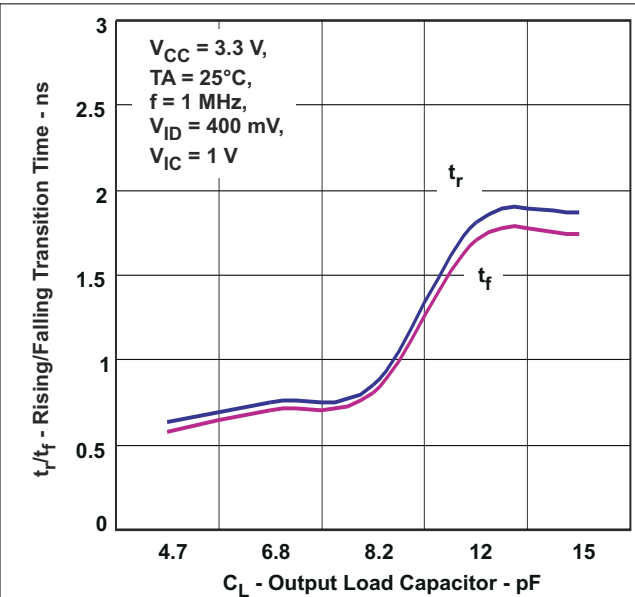


图 5-6. Receiver (Type-1) Transition Time vs Output Load Capacitor

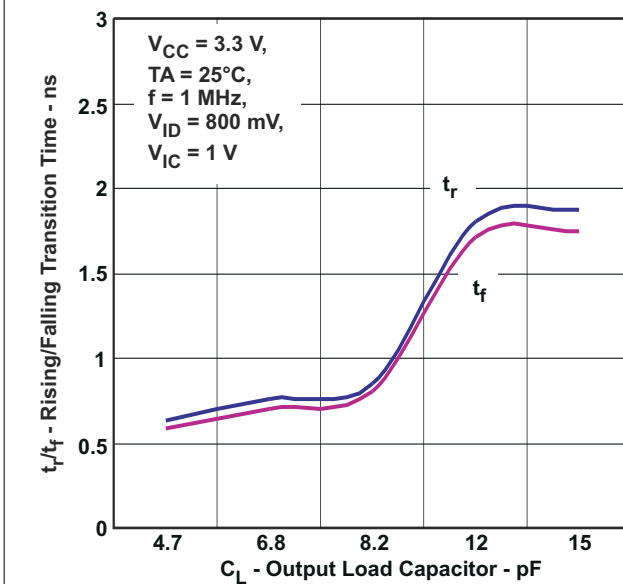


图 5-7. Receiver (Type-2) Transition Time vs Output Load Capacitor

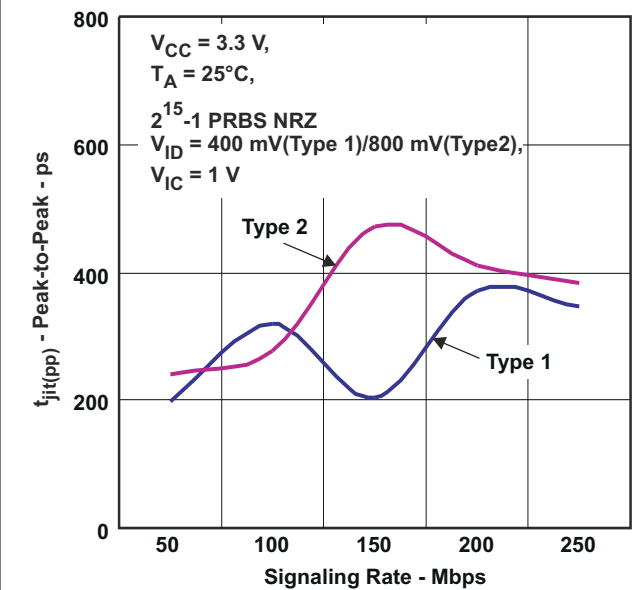
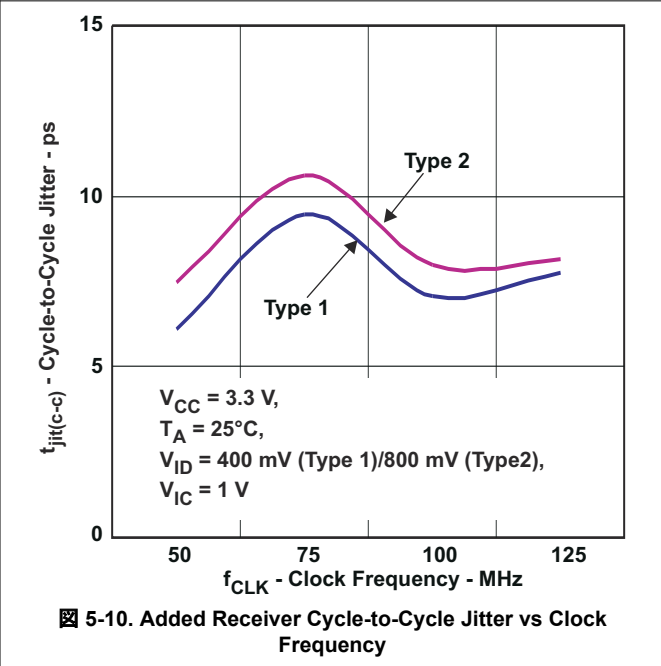
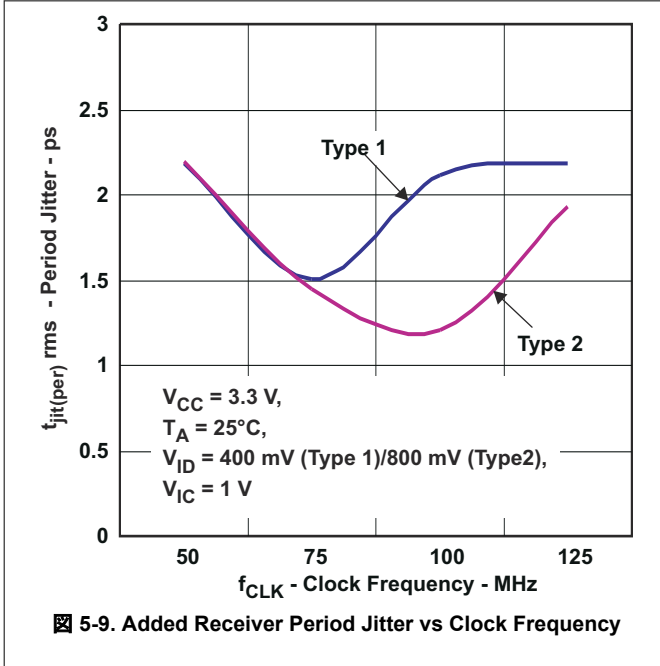
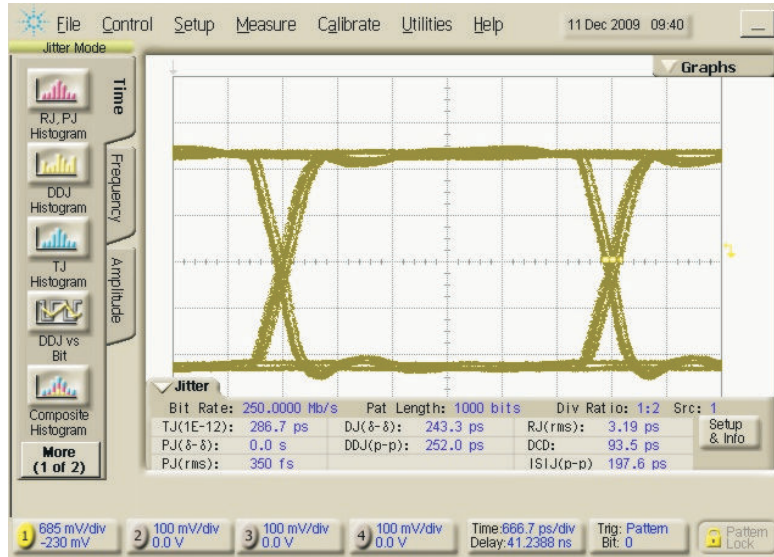


图 5-8. Added Receiver Peak-to-Peak Jitter vs Signaling Rate

5.9 Typical Characteristics (continued)

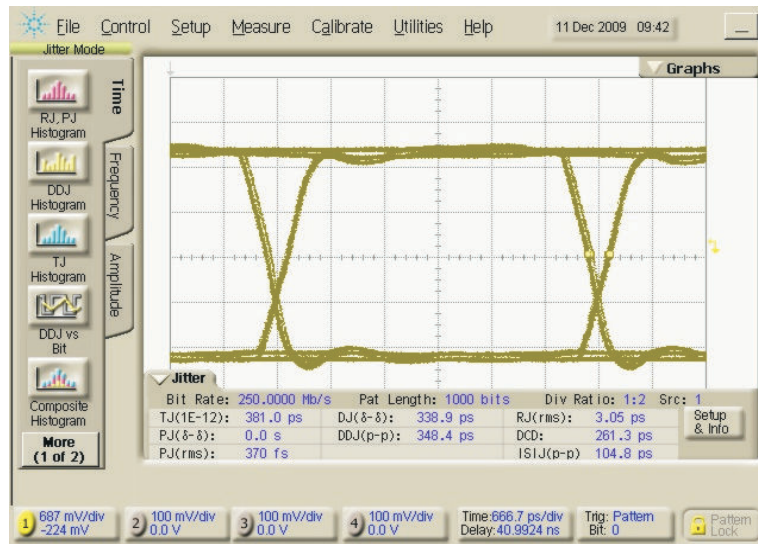


5.9.1 Eye Patterns



5-11. Output ($V_{CC} = 3.3V$, $V_{ID} = 400mV$) 250Mbps 2^{15} -1PRBS, Receiver Type 1

5.9.1 Eye Patterns (continued)



5-12. Output ($V_{CC} = 3.3V$, $V_{ID} = 800mV$) 250Mbps 2^{15} -1PRBS, Receiver Type 2

6 Parameter Measurement Information

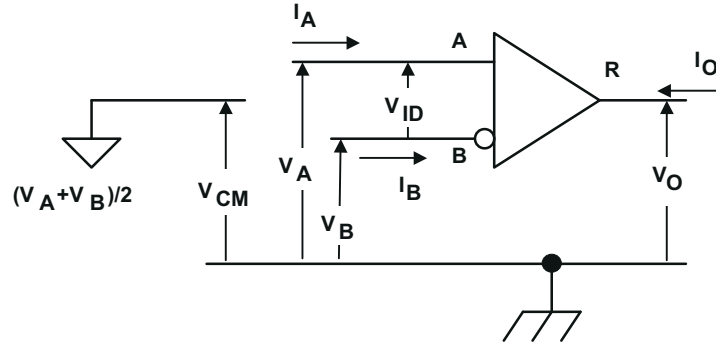


図 6-1. Receiver Voltage and Current Definitions

表 6-1. Type-1 Receiver Input Threshold Test Voltages

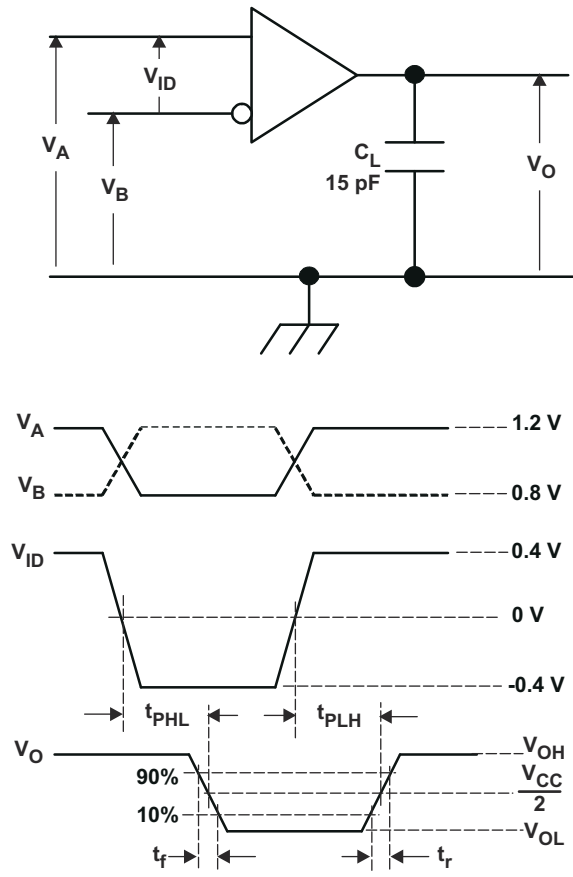
APPLIED VOLTAGES		RESULTING DIFFERENTIAL INPUT VOLTAGE	RESULTING COMMON-MODE INPUT VOLTAGE	RECEIVER OUTPUT ⁽¹⁾
V_{IA}	V_{IB}	V_{ID}	V_{IC}	
2.400	0.000	2.400	1.200	H
0.000	2.400	-2.400	1.200	L
3.400	3.365	0.035	3.3825	H
3.365	3.400	-0.035	3.3825	L
-0.965	-1	0.035	-0.9825	H
-1	-0.965	-0.035	-0.9825	L

(1) H= high level, L = low level, output state assumes receiver is enabled ($\overline{RE} = L$)

表 6-2. Type-2 Receiver Input Threshold Test Voltages

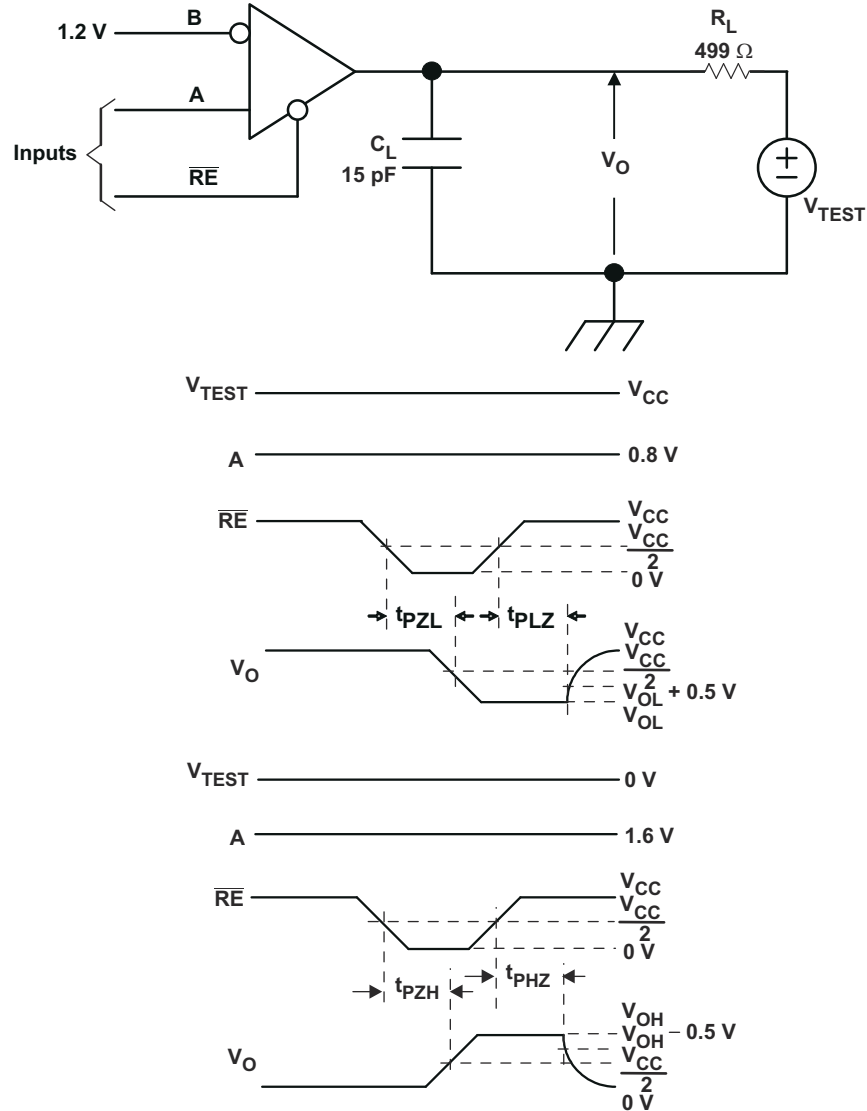
APPLIED VOLTAGES		RESULTING DIFFERENTIAL INPUT VOLTAGE	RESULTING COMMON-MODE INPUT VOLTAGE	RECEIVER OUTPUT ⁽¹⁾
V_{IA}	V_{IB}	V_{ID}	V_{IC}	
2.400	0.000	2.400	1.200	H
0.000	2.400	-2.400	1.200	L
3.400	3.265	0.135	3.3325	H
3.4000	3.335	0.05065	3.3675	L
-0.865	-1	0.135	-0.9325	H
-0.935	-1	0.065	-0.9675	L

(1) H= high level, L = low level, output state assumes receiver is enabled ($\overline{RE} = L$)



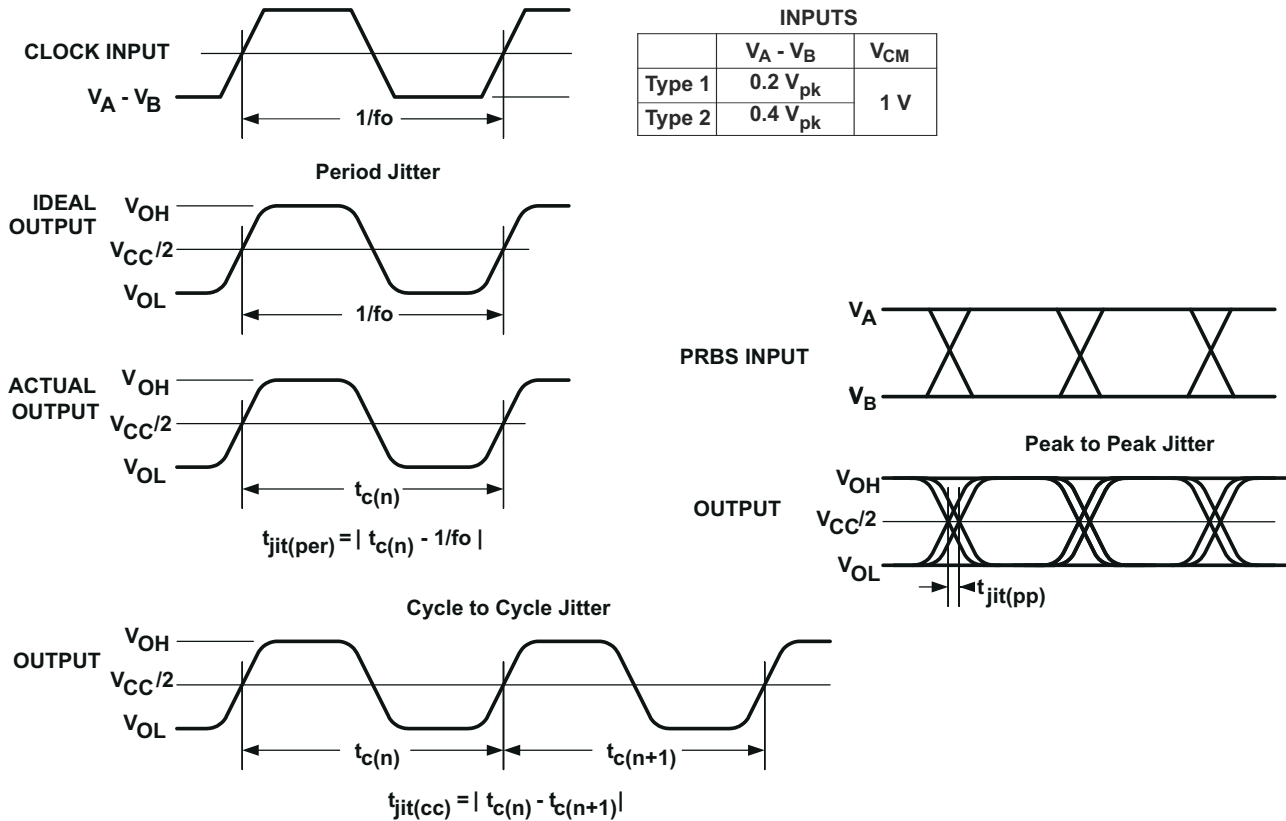
- A. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1\text{ns}$, Frequency = 1MHz, duty cycle = $50 \pm 5\%$. C_L is a combination of a 20%-tolerance, low-loss ceramic, surface-mount capacitor and fixture capacitance within 2 cm of the D.U.T.
- B. The measurement is made on test equipment with a -3dB bandwidth of at least 1GHz.

図 6-2. Receiver Timing Test Circuit and Waveforms



- All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, frequency = 1 MHz, duty cycle = $50 \pm 5\%$.
- R_L is 1% tolerance, metal film, surface mount, and located within 2 cm of the D.U.T
- C_L is the instrumentation and fixture capacitance within 2 cm of the D.U.T. and $\pm 20\%$. The measurement is made on test equipment with a -3 dB bandwidth of at least 1 GHz.

6-3. Receiver Enable/Disable Time Test Circuit and Waveforms



- A. All input pulses are supplied by the Agilent 81250 Parallel BERT Stimulus System with plug-in E4832A.
- B. The cycle-to-cycle jitter measurement is made on a TEK TDS6604 running TDSJIT3 application software.
- C. All other jitter measurements are made with an Agilent Infiniium DCA-J 86100C Digital Communications Analyzer.
- D. Period jitter and cycle-to-cycle jitter are measured using a 125MHz 50 ± 1% duty cycle clock input. Measured over 75K samples.
- E. Deterministic jitter and random jitter are measured using a 250Mbps $2^{15} - 1$ PRBS input. Measured over BER = 10^{-12}

6-4. Receiver Jitter Measurement Waveforms

7 Device Functional Modes

表 7-1. Device Function Table

INPUTS ⁽¹⁾				RECEIVER TYPE	OUTPUT ⁽¹⁾
$V_{ID} = V_A - V_B$	PDN	FSEN	RE		R
$V_{ID} > 35\text{mV}$	H	L	L	Type 1	H
$-35\text{mV} \leq V_{ID} \leq 35\text{mV}$	H	L	L	Type 1	?
$V_{ID} < -35\text{mV}$	H	L	L	Type 1	L
$V_{ID} > 135\text{mV}$	H	H	L	Type 2	H
$65\text{mV} \leq V_{ID} \leq 135\text{mV}$	H	H	L	Type 2	?
$V_{ID} < 65\text{mV}$	H	H	L	Type 2	L
Open Circuit	H	L	L	Type 1	?
Open Circuit	H	H	L	Type 2	L
X	H	X	H	X	Z
X	H	X	OPEN	X	Z
X	L	X	X	X	Z

(1) H=high level, L=low level, Z=high impedance, X=Don't care, ?=indeterminate

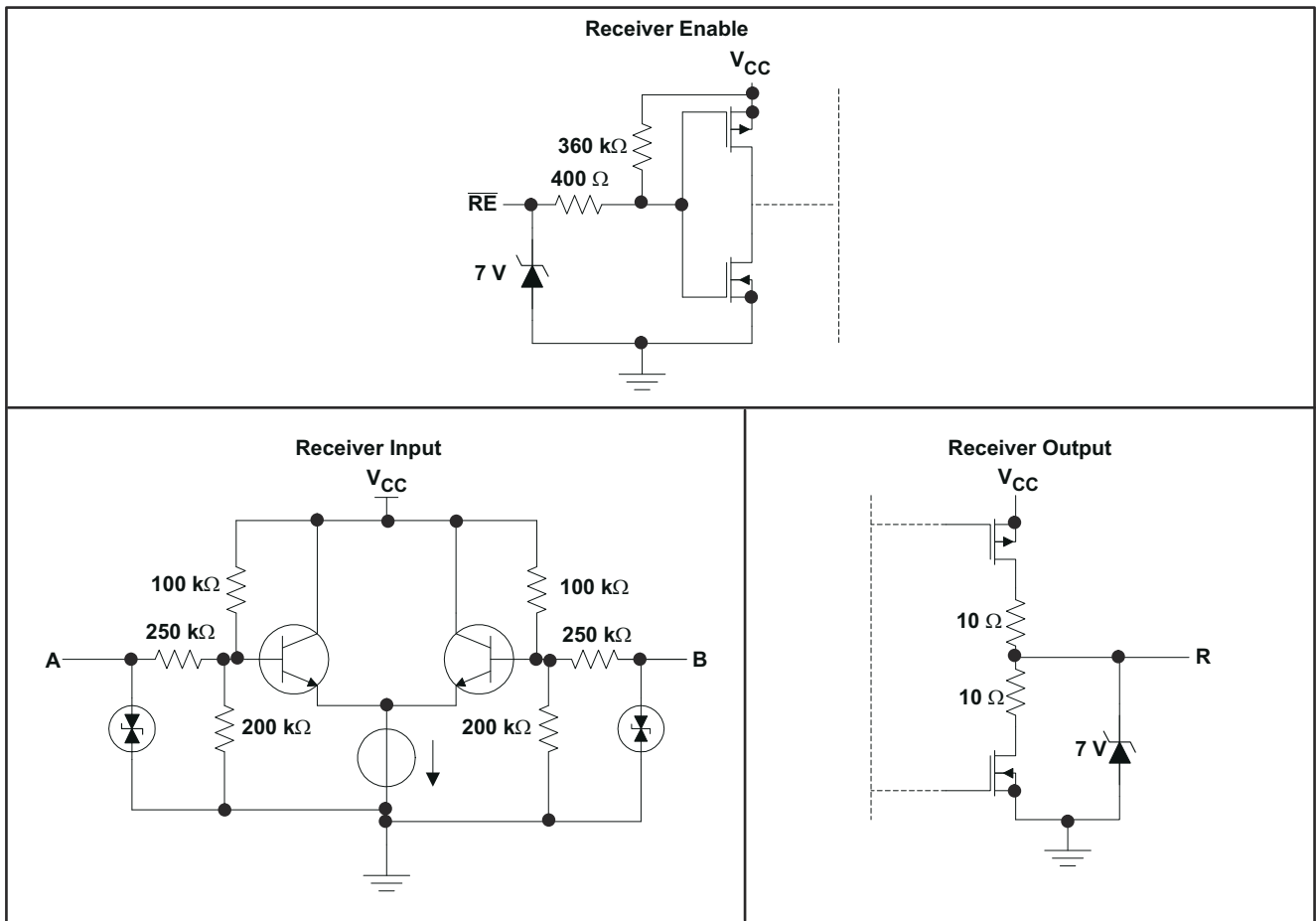


図 7-1. Equivalent Input and Output Schematic Diagrams

8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

8.2 サポート・リソース

テキサス・インスツルメンツ E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、各寄稿者により「現状のまま」提供されるものです。これらはテキサス・インスツルメンツの仕様を構成するものではなく、必ずしもテキサス・インスツルメンツの見解を反映したものではありません。テキサス・インスツルメンツの[使用条件](#)を参照してください。

8.3 Trademarks

PowerPAD™ and テキサス・インスツルメンツ E2E™ are trademarks of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

8.4 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

8.5 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision * (December 2009) to Revision A (March 2024)

Page

- | | |
|--------------------------------------|---|
| • ドキュメント全体にわたって表、図、相互参照の採番方法を変更..... | 1 |
|--------------------------------------|---|

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65MLVD048RGZR	ACTIVE	VQFN	RGZ	48	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	MLVD048	Samples
SN65MLVD048RGZT	ACTIVE	VQFN	RGZ	48	250	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	MLVD048	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65MLVD048RGZR	VQFN	RGZ	48	2500	330.0	16.4	7.3	7.3	1.5	12.0	16.0	Q2
SN65MLVD048RGZT	VQFN	RGZ	48	250	180.0	16.4	7.3	7.3	1.5	12.0	16.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65MLVD048RGZR	VQFN	RGZ	48	2500	356.0	356.0	35.0
SN65MLVD048RGZT	VQFN	RGZ	48	250	210.0	185.0	35.0

GENERIC PACKAGE VIEW

RGZ 48

VQFN - 1 mm max height

7 x 7, 0.5 mm pitch

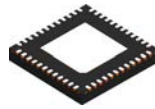
PLASTIC QUADFLAT PACK- NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4224671/A

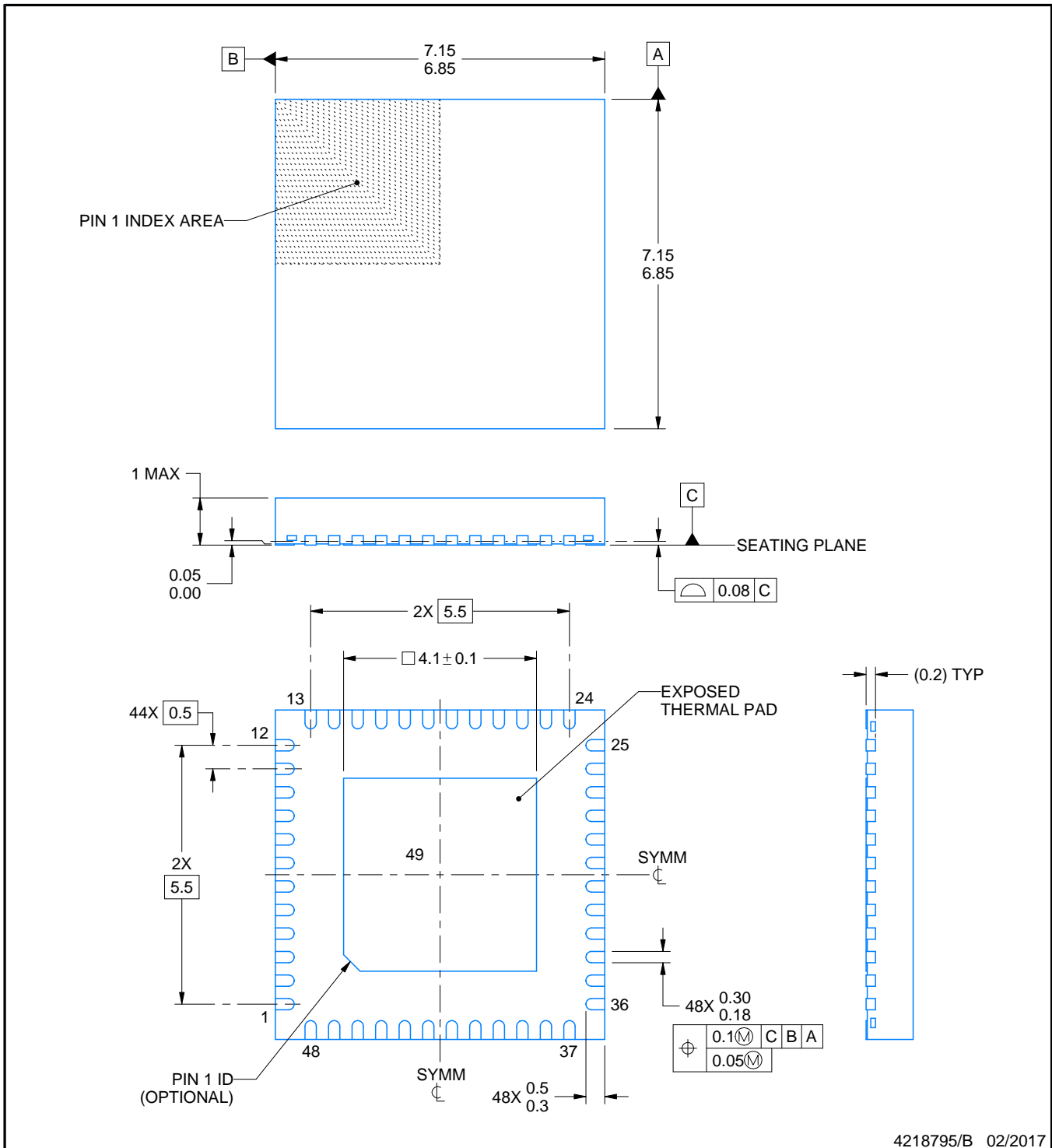
RGZ0048B



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



4218795/B 02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RGZ0048B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:12X



SOLDER MASK DETAILS

4218795/B 02/2017

NOTES: (continued)

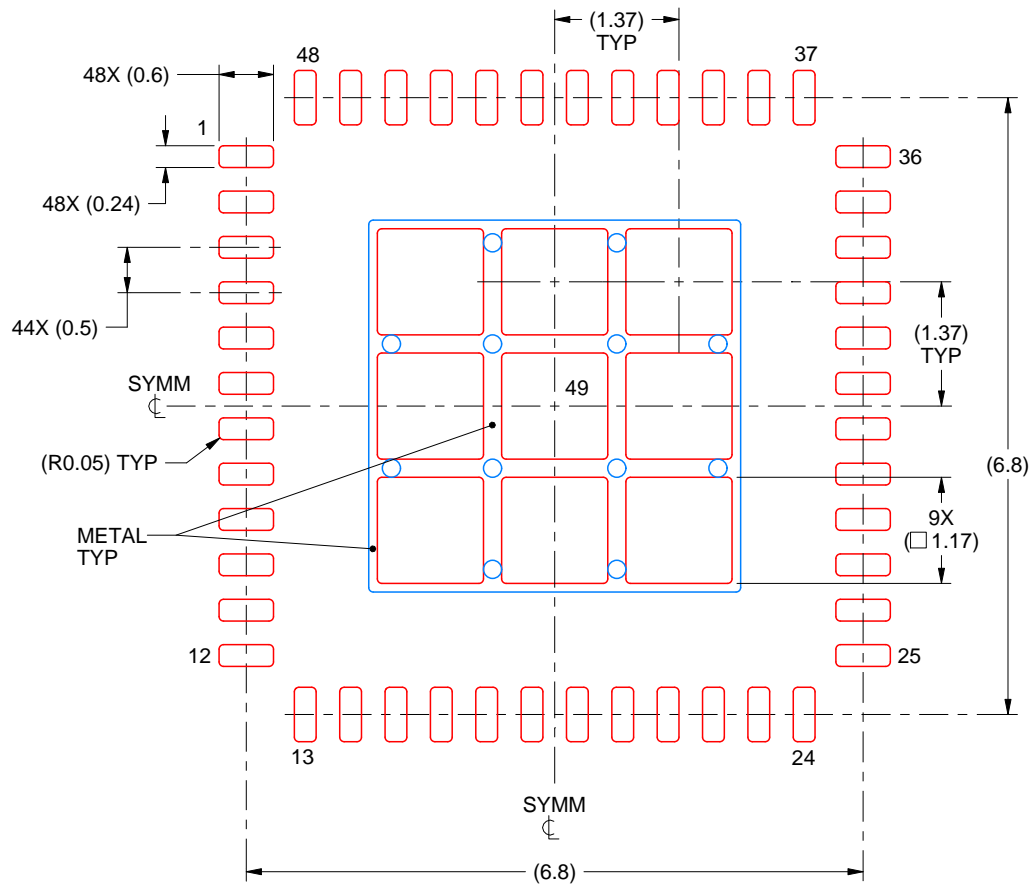
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGZ0048B

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 49
73% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:12X

4218795/B 02/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

重要なお知らせと免責事項

TI は、技術データと信頼性データ（データシートを含みます）、設計リソース（リファレンス・デザインを含みます）、アプリケーションや設計に関する各種アドバイス、Web ツール、安全性情報、その他のリソースを、欠陥が存在する可能性のある「現状のまま」提供しており、商品性および特定目的に対する適合性の黙示保証、第三者の知的財産権の非侵害保証を含むいかなる保証も、明示的または黙示的にかかわらず拒否します。

これらのリソースは、TI 製品を使用する設計の経験を積んだ開発者への提供を意図したものです。(1) お客様のアプリケーションに適した TI 製品の選定、(2) お客様のアプリケーションの設計、検証、試験、(3) お客様のアプリケーションに該当する各種規格や、その他のあらゆる安全性、セキュリティ、規制、または他の要件への確実な適合に関する責任を、お客様のみが単独で負うものとし、

上記の各種リソースは、予告なく変更される可能性があります。これらのリソースは、リソースで説明されている TI 製品を使用するアプリケーションの開発の目的でのみ、TI はその使用をお客様に許諾します。これらのリソースに関して、他の目的で複製することや掲載することは禁止されています。TI や第三者の知的財産権のライセンスが付与されている訳ではありません。お客様は、これらのリソースを自身で使用した結果発生するあらゆる申し立て、損害、費用、損失、責任について、TI およびその代理人を完全に補償するものとし、TI は一切の責任を拒否します。

TI の製品は、[TI の販売条件](#)、または [ti.com](#) やかかる TI 製品の関連資料などのいずれかを通じて提供する適用可能な条項の下で提供されています。TI がこれらのリソースを提供することは、適用される TI の保証または他の保証の放棄の拡大や変更を意味するものではありません。

お客様がいかなる追加条項または代替条項を提案した場合でも、TI はそれらに異議を唱え、拒否します。

郵送先住所：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024, Texas Instruments Incorporated